# mail

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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0910 - 60M

60 Watts - 40 Volts, 150µs, 5% Radar 890 - 1000 MHz

<b>GENERAL DESCRIPTION</b> The 0910-60M is an internally matched, COMMON BASE transistor capable of providing 60 Watts of pulsed RF output power at 150 µs pulse width, 5% duty factor across the band 890 to 1000 MHz. This hermetically solder-sealed transistor is specifically designed for P-Band radar applications. It utilizes gold metallization to provide high reliability.			CASE OUTLINE 55AW-1
ABSOL	UTE MAXIMUM RATIN	NGS	
Maximum Power Dissipation @ 25°C		180 Watts	
Maximum	Voltage and Current		
BVces	Collector to Emitter Voltage	65 Volts	$  \land \land$
BVebo	Emitter to Base Voltage	3.5 Volts	
Ic	Collector Current	8 Amps	
Maximum	Temperatures		
Storage Temperature		$-65 \text{ to} + 200^{\circ}\text{C}$	
Operating Junction Temperature		+ 200°C	

## ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Pout Pg ¶c Pd Rl VSWR <sup>1</sup> VSWRs	Power Out Power Gain Collector Efficiency Pulse Droop Input Return loss Load Mismatch Tolerance Load Mismatch - Stability	Freq = $890 - 1000 \text{ MHz}$ Vcc = $40 \text{ Volts}$ Pin = $9.5 \text{ Watts}$ Pulse Width = $150 \mu s$ Duty Factor = $5\%$	60 8.0 40 -9	8.5 45	84 0.5 3:1 2:1	Watts dB % dB dB

Note 1: Pulse condition of 150µsec, 5%.

Bvces	Collector to Emitter Breakdown	Ic = 40 mA	65		Volts
Ices	Collector to Emitter Leakage	Vce = 40 Volts		10	mA
Iebo	Emitter to Base Leakage	Vebo = 3.0 Volts		8	mA
$\mathbf{\theta}\mathbf{j}\mathbf{c}^1$	Thermal Resistance	Rated Pulse Condition		1.0	°C/W

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*0910–60M* 

### Performance Curves -



#### **Impedance Information**



Frequencies (MHz)	$Z_{Source}(\Omega)$	$Z_{\scriptscriptstyle Load}(\Omega)^{2}$
890	4.4-j4.0	2.8-j0.7
937	4.5-j3.3	2.9-j0.0
1000	4.7-j2.5	3.2+j0.95

Note 2:  $Z_{Load}$  exclusive of C5, C6 and bead on the test circuit





**Test Circuit** 



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0910-60M

**Case Outline** 



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